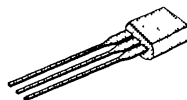


### PRODUCT SUMMARY

| PART NUMBER | $V_{(BR)DSS}$ (V) | $r_{DS(ON)}$ ( $\Omega$ ) | $I_D$ (A) | PACKAGE |
|-------------|-------------------|---------------------------|-----------|---------|
| VN2406L     | 240               | 6                         | 0.22      | TO-92   |
| VN2406M     | 240               | 6                         | 0.25      | TO-237  |

Performance Curves: VNDB24 (See Section 7)

TO-92

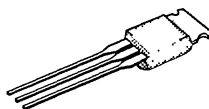


BOTTOM VIEW



1 SOURCE  
2 GATE  
3 DRAIN

TO-237



BOTTOM VIEW



1 SOURCE  
2 GATE  
3 DRAIN

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| PARAMETERS/TEST CONDITIONS                           |                        | SYMBOL                            | VN2406L    | VN2406M | UNITS |
|------------------------------------------------------|------------------------|-----------------------------------|------------|---------|-------|
| Drain-Source Voltage                                 |                        | V <sub>DS</sub>                   | 240        | 240     | V     |
| Gate-Source Voltage                                  |                        | V <sub>GS</sub>                   | ±30        | ±30     |       |
| Continuous Drain Current                             | T <sub>A</sub> = 25°C  | I <sub>D</sub>                    | 0.17       | 0.19    | A     |
|                                                      | T <sub>A</sub> = 100°C |                                   | 0.11       | 0.12    |       |
| Pulsed Drain Current <sup>1</sup>                    |                        | I <sub>DM</sub>                   | 1.7        | 2       |       |
| Power Dissipation                                    | T <sub>A</sub> = 25°C  | P <sub>D</sub>                    | 0.8        | 1       | W     |
|                                                      | T <sub>A</sub> = 100°C |                                   | 0.32       | 0.4     |       |
| Operating Junction and Storage Temperature           |                        | T <sub>J</sub> , T <sub>stg</sub> | -55 to 150 |         | °C    |
| Lead Temperature<br>(1/16" from case for 10 seconds) |                        | T <sub>L</sub>                    | 300        |         |       |

### THERMAL RESISTANCE

| THERMAL RESISTANCE  | SYMBOL     | VN2406L | VN2406M | UNITS              |
|---------------------|------------|---------|---------|--------------------|
| Junction-to-Ambient | $R_{thJA}$ | 156     | 125     | $^\circ\text{C/W}$ |

<sup>1</sup>Pulse width limited by maximum junction temperature

| ELECTRICAL CHARACTERISTICS <sup>1</sup>       |                      |                                                                                                                            |                  | LIMITS |              |      |
|-----------------------------------------------|----------------------|----------------------------------------------------------------------------------------------------------------------------|------------------|--------|--------------|------|
| PARAMETER                                     | SYMBOL               | TEST CONDITIONS                                                                                                            | TYP <sup>2</sup> | VN2406 |              | UNIT |
|                                               |                      |                                                                                                                            |                  | MIN    | MAX          |      |
| STATIC                                        |                      |                                                                                                                            |                  |        |              |      |
| Drain-Source Breakdown Voltage                | V <sub>(BR)DSS</sub> | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 100 μA                                                                             | 270              | 240    |              | V    |
| Gate Threshold Voltage                        | V <sub>GS(th)</sub>  | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 1 mA                                                                  | 1.4              | 0.8    | 2            |      |
| Gate-Body Leakage                             | I <sub>GSS</sub>     | V <sub>DS</sub> = 0 V<br>V <sub>GS</sub> = ±15 V<br>T <sub>J</sub> = 125°C                                                 | ±1<br>±5         |        | ±100<br>±500 | nA   |
| Zero Gate Voltage Drain Current               | I <sub>DSS</sub>     | V <sub>DS</sub> = 120 V<br>V <sub>GS</sub> = 0 V<br>T <sub>J</sub> = 125°C                                                 | 0.01<br>1        |        | 10<br>500    | μA   |
| On-State Drain Current <sup>3</sup>           | I <sub>D(ON)</sub>   | V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 10 V                                                                             | 1.5              | 1      |              | A    |
| Drain-Source On-Resistance <sup>3</sup>       | r <sub>DS(ON)</sub>  | V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 0.1 A                                                                            | 7.5              |        | 10           | Ω    |
|                                               |                      | V <sub>GS</sub> = 10 V                                                                                                     | 5                |        | 10           |      |
|                                               |                      | I <sub>D</sub> = 0.5 A<br>T <sub>J</sub> = 125°C                                                                           | 10.8             |        | 24.7         |      |
| Forward Transconductance <sup>3</sup>         | g <sub>FS</sub>      | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.5 A                                                                             | 530              | 300    |              | mS   |
| Common Source Output Conductance <sup>3</sup> | g <sub>OS</sub>      | V <sub>DS</sub> = 7.5 V, I <sub>D</sub> = 0.5 A                                                                            | 475              |        |              | μS   |
| DYNAMIC                                       |                      |                                                                                                                            |                  |        |              |      |
| Input Capacitance                             | C <sub>iss</sub>     | V <sub>DS</sub> = 25 V<br>V <sub>GS</sub> = 0 V<br>f = 1 MHz                                                               | 110              |        | 125          | pF   |
| Output Capacitance                            | C <sub>oss</sub>     |                                                                                                                            | 30               |        | 50           |      |
| Reverse Transfer Capacitance                  | C <sub>rss</sub>     |                                                                                                                            | 5                |        | 20           |      |
| SWITCHING                                     |                      |                                                                                                                            |                  |        |              |      |
| Turn-On Time                                  | t <sub>d(ON)</sub>   | V <sub>DD</sub> = 60 V, R <sub>L</sub> = 150 Ω<br>I <sub>D</sub> = 0.4 A, V <sub>GEN</sub> = 10 V<br>R <sub>G</sub> = 25 Ω | 3                |        | 8            | ns   |
|                                               | t <sub>r</sub>       |                                                                                                                            | 2                |        | 8            |      |
| Turn-Off Time                                 | t <sub>d(OFF)</sub>  | (Switching time is essentially independent of operating temperature)                                                       | 13               |        | 23           |      |
|                                               | t <sub>f</sub>       |                                                                                                                            | 9                |        | 34           |      |

- NOTES: 1.  $T_A = 25^\circ\text{C}$  unless otherwise noted.  
2. For design aid only, not subject to production testing.  
3. Pulse test;  $PW = 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .